

INTEGRATED CIRCUIT AMPLIFIER FOR IN THE EAR HEARING AID

Monolithic semiconductor integrated-circuit amplifier in a plastic envelope, primarily intended for in the ear hearing aids.

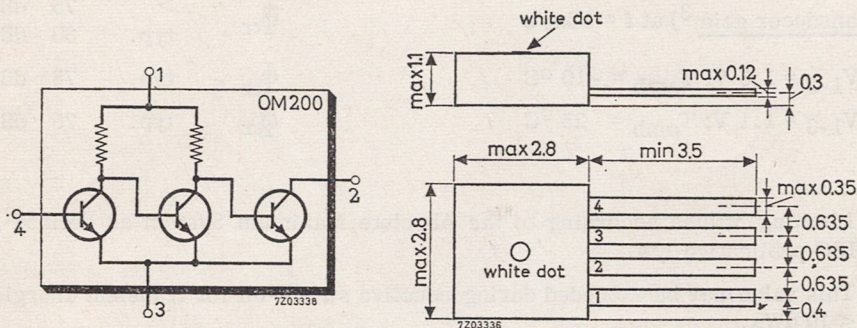
QUICK REFERENCE DATA

For meaning of symbols: see page 3 fig.1.

Supply voltage	V_{1-3}	max.	5 V
Output current	I_2	max.	5 mA
In a practical circuit as given at page 3 fig.1:			
Total supply current	I_{tot}	typ.	1 mA
Transducer gain	$\bar{Q}_{tr}$	>	75 dB
		typ.	80 dB
Power output at $d_{tot} = 10\%$	P_o	>	0.2 mW
Frequency cut-off (-3 dB)	f_c	>	20 kc/s
Total device dissipation	P_{tot}	max.	25 mW

MECHANICAL DATA

Dimensions in mm



The sealing of the plastic envelope withstands the accelerated damp heat test of IEC recommendation 68 (test D, severity IV, 6 cycles).

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RATINGS (Limiting values) ¹⁾
(for meaning of symbols see page 3, fig.1)

Voltages

Supply voltage	V_{1-3}	max.	5 V
Output voltage	V_{2-3}	max.	5 V ²⁾
Input voltage	$-V_{4-3}$	max.	5 V

Currents

Output current	I_2	max.	5 mA
Input current	I_4	max.	5 mA

Dissipation

Total device dissipation (See page A)	P_{tot}	max.	25 mW
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Temperatures

Storage temperature	T_{stg}	-20 to +80	°C
Ambient temperature	T_{amb}	max.	80 °C

CHARACTERISTIC RANGE VALUES FOR EQUIPMENT DESIGN

at $V_{1-3} = 1.3$ V and $T_{amb} = 25$ °C unless otherwise specified
 I_2 see fig.1

<u>Supply current</u> (no signal)	I_{tot}	<	1.2 mA
	I_1	typ.	0.34 mA

<u>Transducer gain</u> ³⁾ at $f = 1$ kc/s	Φ_{tr}	>	75 dB
		typ.	80 dB
$V_{1-3} = 1.3$ V; $T_{amb} = -10$ °C	Φ_{tr}	typ.	78 dB
$V_{1-3} = 1.1$ V; $T_{amb} = 25$ °C	Φ_{tr}	typ.	76 dB

¹⁾ Limiting values according to the Absolute Maximum System as defined in IEC publication 134.

²⁾ This value may be exceeded during inductive switch-off for transient energies < 10 μ Ws.

³⁾ The transducer gain is defined as the ratio of the output power in the load of $Z = 1.5$ k Ω and the available input power of the source with $R_S = 5$ k Ω

$$\Phi_{tr} = \frac{P_o}{V_i^2 / 4R_S}$$

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CHARACTERISTIC RANGE VALUES FOR EQUIPMENT DESIGN (continued)at $V_{1-3} = 1.3 \text{ V}$ and $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$ unless otherwise specified I_2 see figure 1Total distortion at $f = 1 \text{ kc/s}$ $P_O = 100 \mu\text{W}$

d_{tot}	typ.	4 %
	<	6 %

 $P_O = 200 \mu\text{W}$

d_{tot}	<	10 %
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Noise figure at $R_S = 5 \text{ k}\Omega$

bandwidth = 400 to 3200 c/s

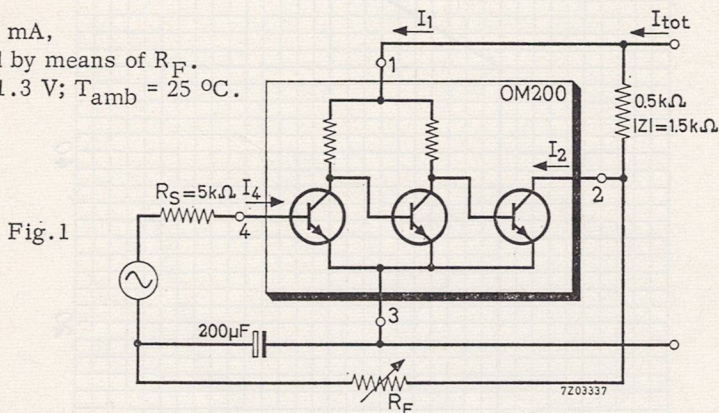
F	<	6 dB
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Frequency cut-off (-3 dB)

f_c	>	20 kc/s
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Value of R_F to adjust I_2 at 0.7 mA

R_F	>	50 k Ω
	typ.	300 k Ω
	<	700 k Ω

 $I_2 = 0.7 \text{ mA}$,adjusted by means of R_F . $V_{1-3} = 1.3 \text{ V}$; $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$.**SOLDERING RECOMMENDATION****A: Iron soldering**

At a maximum iron temperature of $300 \text{ }^{\circ}\text{C}$ the maximum permissible soldering time is 3 seconds, provided the soldering spot is at least 0.5 mm from the seal and the leads are not soldered at the same time. Soldering in immediate subsequence is allowed.

B: Dip soldering

At a maximum solder temperature of $250 \text{ }^{\circ}\text{C}$ the maximum permissible soldering time is 3 seconds, provided the soldering spot is at least 0.5 mm from the seal.

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